

VHF VARIABLE CAPACITANCE DIODE

The BB619 is a VHF variable capacitance diode in planar technology with a very high capacitance ratio intended for VHF-band B up to 460 MHz in all-band tuners.

The diode is encapsulated in a hermetically sealed SOD123 plastic envelope suitable for surface mounting.

QUICK REFERENCE DATA

Continuous reverse voltage	V_R	max.	30 V
Reverse current at $V_R = 30$ V	I_R	max.	10 nA
Diode capacitance at $f = 1$ MHz at $V_R = 28$ V	C_d		2.4 to 2.9 pF
Capacitance ratio at $f = 1$ MHz	$C_d (V_R = 1 \text{ V})$	min.	12.5
	$C_d (V_R = 28 \text{ V})$	typ.	14
Series resistance at $f = 100$ MHz V_R is that value at which $C_d = 30$ pF	r_s	typ.	0.7 Ω

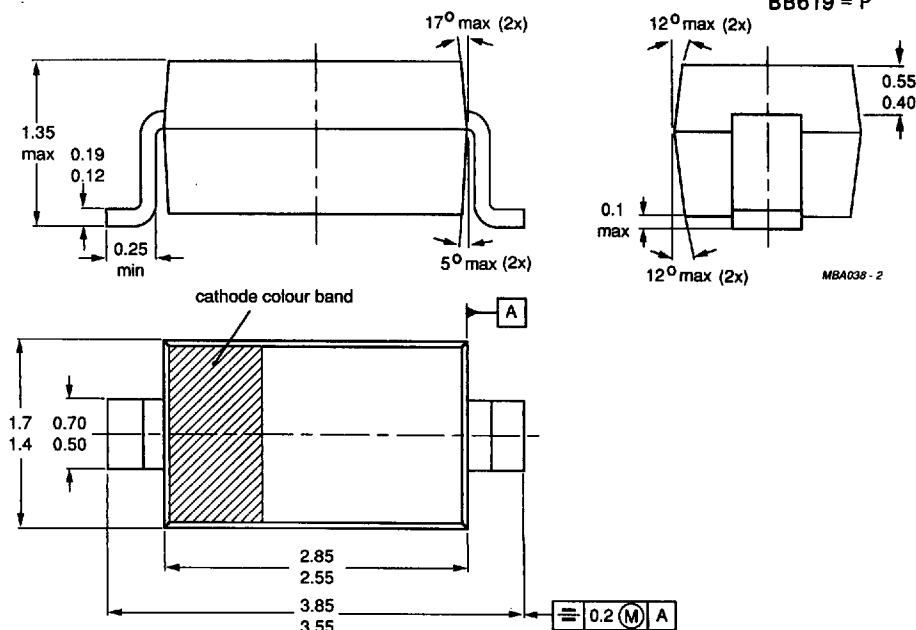
MECHANICAL DATA

Fig.1 SOD123.

Dimensions in mm

Marking code

BB619 = P



Cathode indicated by a yellow band.

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Continuous reverse voltage	V_R	max.	30 V
Reverse voltage (peak value)	V_{RM}	max.	30 V
Forward current (DC)	I_F	max.	20 mA
Storage temperature range	T_{stg}		-55 to + 150 °C
Operating ambient temperature range	T_{amb}		-55 to + 125 °C

CHARACTERISTICS

 $T_{amb} = 25\text{ °C}$ unless otherwise specified

Reverse current

 $V_R = 30\text{ V}$
 I_R max. 10 nA

 $V_R = 30\text{ V}; T_{amb} = 85\text{ °C}$
 I_R max. 200 nA

Reverse breakdown voltage

 $I_R = 10\text{ }\mu\text{A}$
 $V_{(BR)R}$ min. 30 V

Diode capacitance at $f = 1\text{ MHz}$
 $V_R = 1\text{ V}$
 C_d 33.5 to 41 pF

 $V_R = 28\text{ V}$
 C_d 2.4 to 2.9 pF

Capacitance ratio at $f = 1\text{ MHz}$
 $\frac{C_d(V_R = 1\text{ V})}{C_d(V_R = 28\text{ V})}$ min. 12.5

typ. 14

Tolerance of capacitance difference between
two diodes of $V_R = 1.0\text{ V}$ to 28 V

 $\frac{\Delta C}{C}$ max. 2.5 %

Series resistance

at $f = 100\text{ MHz}$ and at that value of V_R at
which $C_d = 30\text{ pF}$
 r_s typ. 0.7 Ω

Series inductance

 L_s typ. 2.8 nH